

N-Channel JFET15 V, 10 to 20 mA, 38 mS, CP

2SK2394

Features

- Large |yfs|
- Small Ciss
- Small-Sized Package Permitting 2SK2394-Applied Sets to be Made Small Slim
- Ultralow Noise Figure
- This is a Pb-Free Device

Applications

- AM Tuner RF Amplifier
- Low-Noise Amplifier

ABSOLUTE MAXIMUM RATINGS at T_A = 25°C

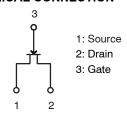
Symbol	Parameter	Value	Unit
V _{DSX}	Drain-to-Source Voltage	15	V
V_{GDS}	Gate-to-Drain Voltage	-15	V
I _G	Gate Current	10	mA
I _D	Drain Current	50	mA
P_{D}	Allowable Power Dissipation	200	mW
T_J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

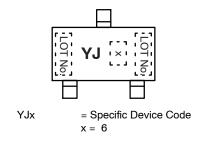


SC-59-3 318BJ

ELECTRICAL CONNECTION



MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
2SK2394-6-TB-E	SC-59-3 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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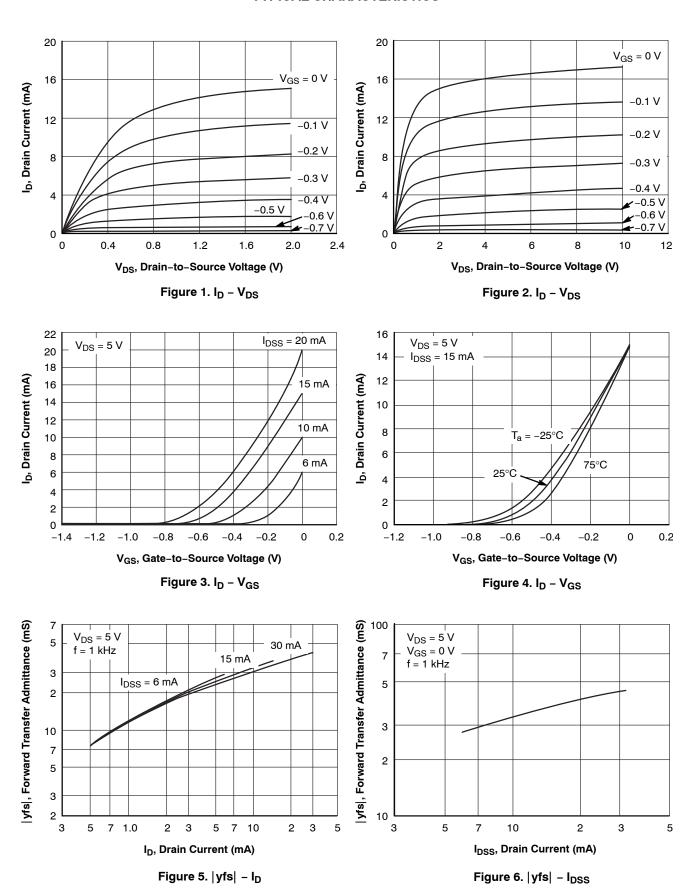
ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$

			Ratings			
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{(BR)GDS}	Gate-to-Drain Breakdown Voltage	$I_G = -10 \mu A, V_{DS} = 0 V$	-15	-	_	V
I _{GSS}	Gate Cutoff Current	V _{GS} = -10 V, V _{DS} = 0 V	-	-	-1.0	nA
V _{GS(off)}	Cutoff Voltage	$V_{DS} = 5 \text{ V}, I_D = 100 \mu\text{A}$	-0.3	-0.7	-1.0	V
I _{DSS}	Drain Current	V _{DS} = 5 V, V _{GS} = 0 V	10	-	20	mA
yfs	Forward Transfer Admittance	V _{DS} = 5 V, V _{GS} = 0 V, f = 1 kHz	20	38	_	mS
C _{iss}	Input Capacitance	V _{DS} = 5 V, V _{GS} = 0 V, f = 1 MHz	-	10.0	_	pF
C _{rss}	Reverse Transfer Capacitance		-	2.9	_	pF
NF	Noise Figure	V_{DS} = 5 V, R_g = 1 k Ω , I_D = 1 mA, f = 1 kHz	-	1.0	-	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

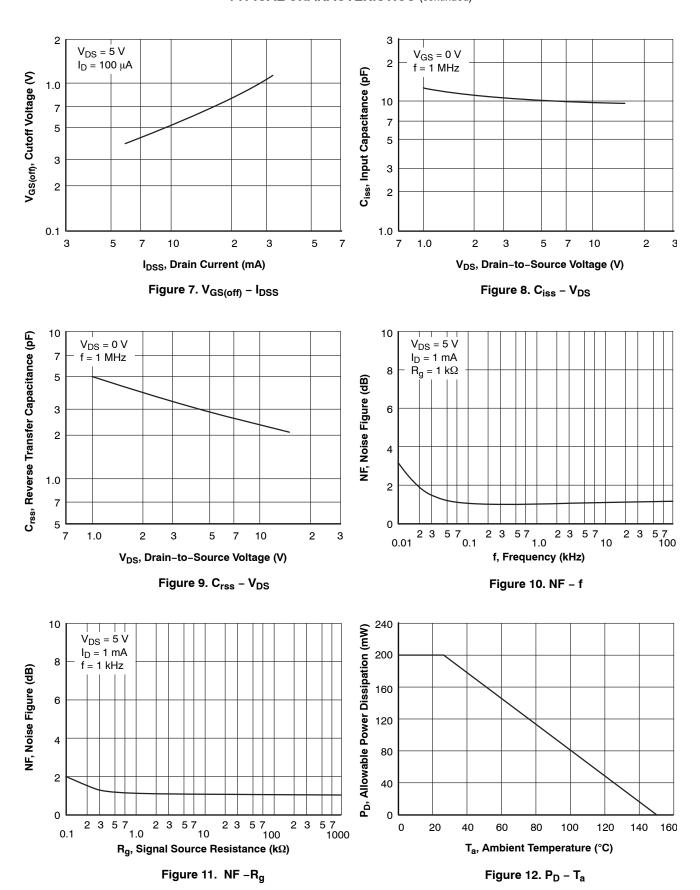
2SK2394

TYPICAL CHARACTERISTICS



2SK2394

TYPICAL CHARACTERISTICS (continued)









E1

е

TOP VIEW

SIDE VIEW

SC-59 / CP3 CASE 318BJ ISSUE O

DATE 09 JAN 2015



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

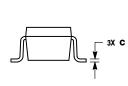
 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER SIDE.

 4. DIMENSIONS D AND E1 ARE MEASURED AT THE OUTERMOST EXTREME OF THE PLASTIC BODY.

 5. DIMENSIONS D AND CA ADDLY TO THE SI AT SECTION OF THE
- DIMENSIONS 6 AND 6 APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.20 FROM THE TIP.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.95	1.35	
A1	0.00	0.10	
A2	0.20	0.40	
b	0.35	0.50	
С	0.10	0.20	
D	2.75	3.05	
E	2.30	2.70	
E1	1.35	1.65	
е	0.95 BSC		
L	0.35	0.75	



END VIEW

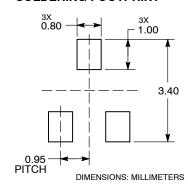
RECOMMENDED SOLDERING FOOTPRINT*

3X L

зх b

⊕ 0.10 M C A

C SEATING PLANE



^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM



= Specific Device Code XXX = Date Code Μ

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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